

RoHS

COMPLIANT

HALOGEN

FREE

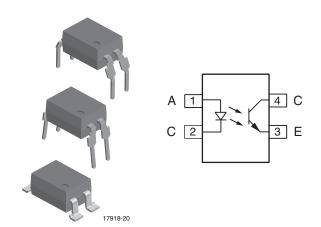
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Vishay Semiconductors

Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}, 110 °C Rated



DESCRIPTION

The 110 °C rated SFH617A (DIP) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package. The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing. Creepage and clearance distances of > 8.0 mm are achieved with option 6.

FEATURES

- Operating temperature from -55 °C to +110 °C
- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- High collector emitter voltage, V_{CEO} = 70 V
- Low saturation voltage
- Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- AC adapter
- SMPS
- PLC
- Factory automation
- · Game consoles

AGENCY APPROVALS

The safety application model number covering all products in this datasheet is SFH617A. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO
- CQC

ORDERING INFORMATIO	N				
S F H 6 1 7 A - # X 0 # # T PART NUMBER CTR PACKAGE OPTION TAPE AND REEL Option 7 Option 9 8 mm typ.					
AGENCY CERTIFIED/PACKAGE		CTR	R (%)		
UL, BSI, FIMKO, cUL	40 to 80	63 to 125	100 to 200	160 to 320	
DIP-4	SFH617A-1	SFH617A-2	SFH617A-3	SFH617A-4	
DIP-4, 400 mil, option 6	SFH617A-1X006	SFH617A-2X006	SFH617A-3X006	SFH617A-4X006	
SMD-4, option 7	SFH617A-1X007T	-	SFH617A-3X007T	-	
SMD-4, option 9	-	SFH617A-2X009T	=	-	
VDE, UL, BSI, FIMKO, cUL	40 to 80	63 to 125	100 to 200	160 to 320	
DIP-4	SFH617A-1X001	SFH617A-2X001	SFH617A-3X001	SFH617A-4X001	
DIP-4, 400 mil, option 6	SFH617A-1X016	SFH617A-2X016	SFH617A-3X016	SFH617A-4X016	
SMD-4, option 7	=	SFH617A-2X017T	SFH617A-3X017T (1)	-	
SMD-4, option 9	=	SFH617A-2X019T (1)	-	-	

Notes

Rev. 2.4, 31-Aug-15

- Additional options may be possible, please contact sales office.
- (1) Also available in tubes; do not add T to end.



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		V _R	6	V		
Forward current		I _F	60	mA		
Forward surge current	t _p ≤ 10 μs	I _{FSM}	2.5	Α		
LED power dissipation	at 25 °C	P _{diss}	70	mW		
OUTPUT						
Collector emitter voltage		V _{CEO}	70	V		
Emitter collector voltage		V _{ECO}	7	V		
Collector current		I _C	50	mA		
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA		
Ouput power dissipation	at 25 °C	P _{diss}	150	mW		
COUPLER						
Operation temperature		T _{amb}	- 55 to + 110	°C		
Storage temperature range		T _{stg}	- 55 to + 150	°C		
Soldering temperature (1)	2 mm from case, ≤ 10 s	T _{sld}	260	°C		

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 60 \text{ mA}$		V_{F}		1.35	1.65	٧
Reverse current	V _R = 6 V		I _R		0.01	10	μA
Capacitance	$V_R = 0 V$, $f = 1 MHz$		Co		13		pF
OUTPUT							
Collector emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$		C _{CE}		5.2		pF
Collector emitter leakage current	V _{CE} = 10 V	SFH617A-1	I _{CEO}		2	50	nA
		SFH617A-2	I _{CEO}		2	50	nA
Collector entitter leakage current		SFH617A-3	I _{CEO}		5	100	nA
		SFH617A-4	I _{CEO}		5	100	nA
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, f = 1 \text{ MHz}$		V _{CEsat}	•	0.25	0.4	٧
Coupling capacitance	_		C _C		0.4		pF

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



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CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	SFH617A-1	CTR	40		80	%
		SFH617A-2	CTR	63		125	%
		SFH617A-3	CTR	100		200	%
1 /1		SFH617A-4	CTR	160		320	%
I _C /I _F	I _F = 1 mA, V _{CE} = 5 V	SFH617A-1	CTR	13	30		%
		SFH617A-2	CTR	22	45		%
		SFH617A-3	CTR	34	70		%
		SFH617A-4	CTR	56	90		%

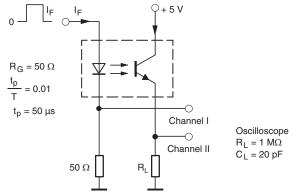
SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Turn-on time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t _{on}		3		μs
Rise time	$I_F = 10$ mA, $V_{CC} = 5$ V, $R_L = 75$ Ω		t _r		2		μs
Turn-off time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t _{off}		2.3		μs
Fall time	$I_F = 10$ mA, $V_{CC} = 5$ V, $R_L = 75$ Ω		t _f		2		μs
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}$		f _{CO}		100		kHz
SATURATED							
	I _F = 20 mA	SFH617A-1	t _{on}		3		μs
Turn-on time	I _F = 10 mA	SFH617A-2	t _{on}		4.2		μs
		SFH617A-3	t _{on}		4.2		μs
	I _F = 5 mA	SFH617A-4	t _{on}		6		μs
	I _F = 20 mA	SFH617A-1	t _r		2		μs
Rise time	I _F = 10 mA	SFH617A-2	t _r		3		μs
nise time		SFH617A-3	t _r		3		μs
	I _F = 5 mA	SFH617A-4	t _r		4.6		μs
	I _F = 20 mA	SFH617A-1	t _{off}		18		μs
Turn-off time	I _F = 10 mA	SFH617A-2	t _{off}		23		μs
Turn-oπ time		SFH617A-3	t _{off}		23		μs
	I _F = 5 mA	SFH617A-4	t _{off}		25		μs
	I _F = 20 mA	SFH617A-1	t _f		11		μs
Fall time	e I _F = 10 mA	SFH617A-2	t _f		14		μs
ran ume		SFH617A-3	t _f		14		μs
	I _F = 5 mA	SFH617A-4	t _f		15		μs





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Fig. 1 - Test Circuit, Non-Saturated Operation

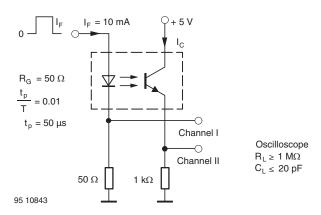


Fig. 2 - Test Circuit, Saturated Operation

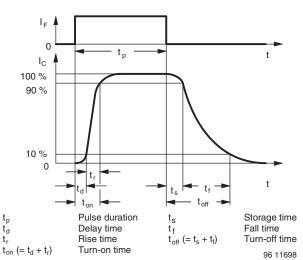


Fig. 3 - Switching Times

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55/115/21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	4470	V _{RMS}
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V _{ISO}	5300	V _{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	8000	V _{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	890	V _{peak}
Isolation resistance	$T_{amb} = 25 ^{\circ}C, V_{IO} = 500 V$	R _{IO}	≥ 10 ¹²	Ω
Isolation resistance	$T_{amb} = 100 ^{\circ}C, V_{IO} = 500 V$	R _{IO}	≥ 10 ¹¹	Ω
Output safety power		P _{SO}	700	mW
Input safety current		I _{SI}	400	mA
Input safety temperature		T _S	175	°C
Creepage distance	DIP-4		≥7	mm
Clearance distance	DIP-4		≥7	mm
Creepage distance	DIP-4, 400 mil, option 6		≥ 8	mm
Clearance distance	DIP-4, 400 mil, option 6		≥8	mm
Creepage distance	SMD-4, option 7 and option 9		≥ 7	mm
Clearance distance	SMD-4, option 7 and option 9		≥7	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance
with the safety ratings shall be ensured by means of protective circuits.



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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

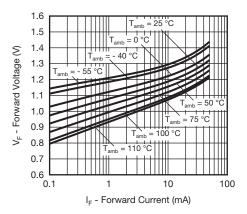


Fig. 4 - Forward Voltage vs. Forward Current

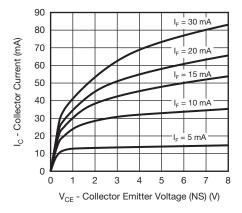


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

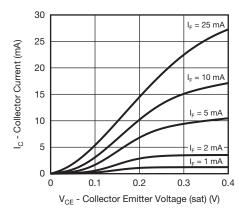


Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)

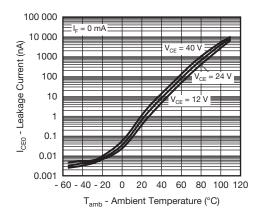


Fig. 7 - Leakage Current vs. Ambient Temperature

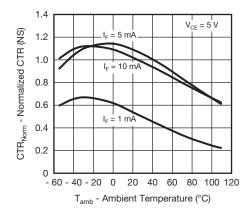


Fig. 8 - Normalized CTR (NS) vs. Ambient Temperature

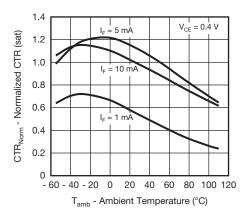


Fig. 9 - Normalized CTR (sat) vs. Ambient Temperature

For technical questions, contact: optocouplera



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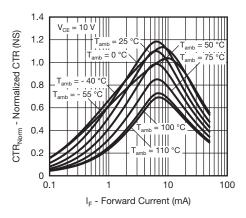


Fig. 10 - Normalized CTR (NS) vs. Forward Current

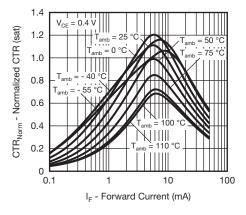


Fig. 11 - Normalized CTR (sat) vs. Forward Current

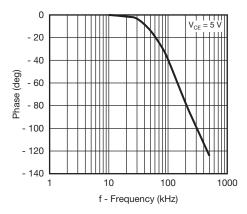


Fig. 12 - CTR Frequency vs. Phase Angle

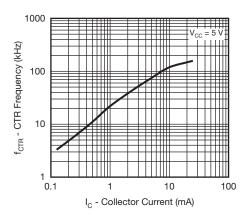


Fig. 13 - CTR Frequency vs. Collector Current

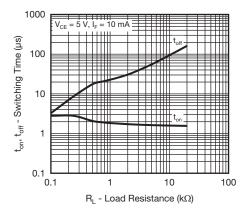
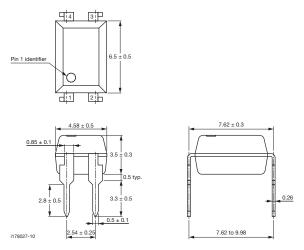


Fig. 14 - Switching Time vs. Load Resistance

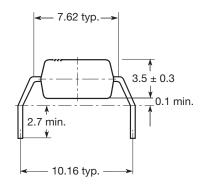


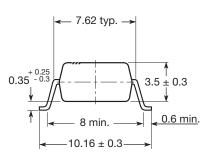
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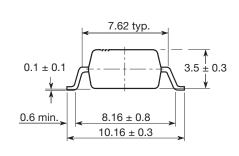
PACKAGE DIMENISONS in millimeters

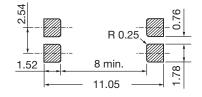


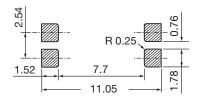
Option 6 Option 7 Option 9











20802-28

PACKAGE MARKING



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.



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SOLDER PROFILES

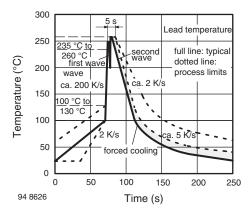


Fig. 15 - Wave Soldering Double Wave Profile According to J-STD-020 for DIP-8 Devices

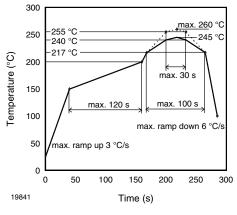


Fig. 16 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD-8 Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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Revision: 02-Oct-12 Document Number: 91000